DBF2005 THRU DBF210

SINGLE-PHASE GLASS PASSIVATED SILICON SURFACE MOUNT BRIDGE RECTIFIER

Reverse Voltage - 50 to 1000 V Forward Current - 2 A

Features

- Low forward voltage drop
- · Glass passivated chip junction
- High surge current capability

Mechanical Data

- Case: Molded plastic, DBF
- Terminal: Leads solderable per MIL-STD-002, method 208 guaranteed
- Mounting position: Any

DBF

All Dimensions in mm

Maximum Ratings and Electrical Characteristics

inductive load. For capacitive load, derate current by 20%. DBF201 DBF210 Units Symbols DBF2005 DBF202 DBF204 DBF206 DBF208 Parameter Maximum Recurrent Peak Reverse Voltage V_{RRM} 50 100 200 400 600 800 1000 V 35 70 140 280 420 560 700 V Maximum RMS Voltage V_{RMS} \overline{V}_{DC} 600 50 100 200 400 800 1000 V Maximum DC Blocking Voltage Maximum Average Forward Rectified Current 2 А I_{F(AV)} at $T_c = 110$ °C Peak Forward Surge Current 8.3 ms Single Half-sine I_{FSM} 75 А -wave Superimposed on Rated Load (JEDEC Method) V Maximum Forward Voltage at 2 A DC VF 1.1 Maximum Reverse Current $T_j = 25^{\circ}C$ 5 I_R μA at Rated DC Blocking Voltage T_j = 125°C 500 Typical Junction Capacitance C_j 35 pF Typical Thermal Resistance $R_{\theta JA}$ °C/W 55 Typical Thermal Resistance $R_{\theta JL}$ °C/W 15 Typical Thermal Resistance $R_{\theta JC}$ °C/W 10 Operating and Storage Temperature Range °C Tj,T_{stg} - 55 to + 150

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 Vdc.



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